## EE 381 Electric and Magnetic Fields Quiz #10 (Fall 2024)

Name Key A

Instructions: Closed book & notes. Place answers in indicated spaces and show all work for credit.

Eager for a snack, Emma Engineer places cranberry sauce (a tart mixture of cranberries, water, spices & sugar  $\Rightarrow \varepsilon = 64\varepsilon_0$ ,  $\sigma = 0.01$  S/m) between large circular metal plates at z = 0 and z = 2 cm. To warm the sauce, she connects a dual-channel DC power supply to the plates, lower plate at +15 V and upper plate at -10 V. After 2 seconds, does Laplace's or Poisson's equation apply? Justify answer by finding the relaxation time for any initial free charges in the sauce. Find the potential, electric field, and current density in the cranberry sauce at z = 0.4 cm. Extra credit- Determine the *power density* in the sauce.

After 25, any initial Po would be Cyl. coordinates long gone => Po=0=> Luplace's Egn  $p^{2}V = \frac{1}{p} \frac{d}{dp} (p \frac{\partial V}{\partial p}) + \frac{1}{p^{2}} \frac{\partial^{2}V}{\partial g^{2}} + \frac{\partial^{2}V}{\partial z^{2}} = 0$ no change unt pay S d 2 d 2 = S o d 2 > d V = A > S d V d 2 = S A d 2 -> V=AZ+B @Z=0 V=15=A(0)+B=> B=15V (w == 0.02m, V=-10 = A/0.02)+15 -> A =-1750 /m V(2) = -12502+15V0=2=0.02m V(0.004m)=10V E=- TV= - Qz dz (-1250+15) = Qz 1250 /m 06262cm J=0 == 0.01 az 1250 = az 12.5 1/m2052 62 cm Extrn: wp=0/E/2=0.01(1250)2=15,625 W/m3

Laplace's or Poisson's equation? (Circle correct answer)

 $T_{\rm relax} = 56,67.05$ 

V(z=0.4 cm) = 100 V

 $\overline{E}$   $(z=0.4 \text{ cm}) = \frac{\widehat{a}_{\overline{z}}}{250} \frac{1250}{\text{m}}$ 

 $\bar{J}$  (z=0.4 cm) =  $\hat{Q}$  = 12.5  $\frac{A_{m}}{2}$ 

Extra - power density = 15,625  $\frac{1}{m}$   $\frac{3}{m}$ 

## Cylindrical Coordinates $(\rho, \phi, z)$

$$\begin{split} d\overline{l} &= d\rho \, \hat{a}_{\rho} + \rho d\phi \, \hat{a}_{\phi} + dz \, \hat{a}_{z} \\ d\overline{s}_{\rho} &= \rho \, d\phi \, dz \, \hat{a}_{\rho} \quad d\overline{s}_{\phi} = d\rho \, dz \, \hat{a}_{\phi} \quad d\overline{s}_{z} = \rho \, d\rho \, d\phi \, \hat{a}_{z} \\ dv &= \rho \, d\rho \, d\phi \, dz \\ \overline{r} &= \rho \, \hat{a}_{\rho} + z \, \hat{a}_{z} \quad \text{(Note: } \hat{a}_{\rho} \text{ has } \phi \text{ dependence)} \\ \overline{\nabla} \Phi &= \, \hat{a}_{\rho} \frac{\partial \Phi}{\partial \rho} + \hat{a}_{\phi} \frac{1}{\rho} \frac{\partial \Phi}{\partial \phi} + \hat{a}_{z} \frac{\partial \Phi}{\partial z} \\ \overline{\nabla} \bullet \overline{A} &= \frac{1}{\rho} \frac{\partial \left(\rho \, A_{\rho}\right)}{\partial \rho} + \frac{1}{\rho} \frac{\partial A_{\phi}}{\partial \phi} + \frac{\partial A_{z}}{\partial z} \\ \overline{\nabla} \times \overline{A} &= \, \hat{a}_{\rho} \left( \frac{1}{\rho} \frac{\partial A_{z}}{\partial \phi} - \frac{\partial A_{\phi}}{\partial z} \right) + \hat{a}_{\phi} \left( \frac{\partial A_{\rho}}{\partial z} - \frac{\partial A_{z}}{\partial \rho} \right) + \hat{a}_{z} \left( \frac{1}{\rho} \frac{\partial \left(\rho \, A_{\phi}\right)}{\partial \rho} - \frac{1}{\rho} \frac{\partial A_{\rho}}{\partial \phi} \right) \\ \nabla^{2} \Phi &= \, \frac{1}{\rho} \frac{\partial}{\partial \rho} \left( \rho \, \frac{\partial \Phi}{\partial \rho} \right) + \frac{1}{\rho^{2}} \frac{\partial^{2} \Phi}{\partial \phi^{2}} + \frac{\partial^{2} \Phi}{\partial z^{2}} \end{split}$$

permeability of free space:  $\mu_0 = 4\pi \cdot 10^{-7}$  H/m permittivity of free space:  $\epsilon_0 = 8.8542 \times 10^{-12}$  F/m

<u>Coulomb's Law</u>: point charges  $\overline{F}_{12} = \frac{Q_1 Q_2}{4\pi\varepsilon_0 R^2} \hat{a}_{R12} = \frac{Q_1 Q_2 (\overline{r_2} - \overline{r_1})}{4\pi\varepsilon_0 |\overline{r_2} - \overline{r_1}|^3}$  (N) force on  $Q_2$  due to  $Q_1$ 

Electric Field  $\overline{E} = \overline{F} / q = -\overline{\nabla} V$  is conservative (i.e.,  $\overline{\nabla} \times \overline{E} = 0$  and  $\oint_c \overline{E} \cdot d\overline{l} = 0$ ).

point charges: 
$$\overline{E} = \frac{Q}{4\pi\varepsilon_0 R^2} \hat{a}_R = \frac{Q(\overline{r} - \overline{r}')}{4\pi\varepsilon_0 |\overline{r} - \overline{r}'|^3}$$
 (V/m) &  $\overline{E} = \sum_{k=1}^N \frac{Q_k(\overline{r} - \overline{r}_k)}{4\pi\varepsilon_0 |\overline{r} - \overline{r}_k|^3}$  (V/m)

volume charge density:  $\overline{E} = \int_{v'} \frac{\rho_v(\overline{r} - \overline{r'}) dv'}{4\pi\varepsilon_0 |\overline{r} - \overline{r'}|^3}$  (V/m) where  $\rho_v$  can be a function of position (i.e.  $\overline{r'}$ ).

Electric Flux Density:  $\overline{D} = \varepsilon_r \varepsilon_0 \overline{E} = \varepsilon \overline{E}$  (C/m<sup>2</sup>) and Electric Flux:  $\psi = \int \overline{D} \cdot d\overline{s}$  (C)

Gauss' Law: Amount of electric flux through a <u>closed</u> surface is equal to amount of charge contained within surface.  $\psi = \oint_{\mathbb{R}} \overline{D} \cdot d\overline{s} = Q_{\text{enc}}$  (C). In differential/point form  $\nabla \cdot \overline{D} = \rho_{\nu}$ 

Charge density in conductive materials  $\rho_v = \rho_v(0) e^{-t/T_r}$  where  $T_r = \varepsilon / \sigma$  is the relaxation time.

Conduction current density:  $\overline{J} = \sigma \overline{E}$  (A/m<sup>2</sup>) and electrical current  $I = \int_{s} \overline{J} \cdot d\overline{s} = \frac{dQ}{dt}$  (A)

Resistance:  $R = \frac{V}{I} = \frac{l}{\sigma S}$  ( $\Omega$ ) where l is length,  $\sigma$  is conductivity (S/m), and S is surface area

Perfect electrical conductor (PEC)-  $\overline{E}_{\text{inside}} = 0$ ,  $\rho_{v, \text{ inside}} = 0$ , and  $V_{ab} = 0$  for any points a and b inside.

Power dissipation:  $P = \int \overline{E} \cdot \overline{J} \, dv = \int \sigma |\overline{E}|^2 \, dv$  (W) and power density  $w_p = \overline{E} \cdot \overline{J} = \sigma |\overline{E}|^2$  (W/m<sup>3</sup>)

Poisson's equation  $\nabla^2 V = -\rho_v / \varepsilon$  and Laplace's equation  $\nabla^2 V = 0$ .

$$\underline{\text{Capacitance-}} \ C = \frac{Q}{V} = \frac{\oint_{s} \overline{D} \cdot d\overline{s}}{-\int_{\text{low}}^{\text{high}} \overline{E} \cdot d\overline{l}} = \frac{\varepsilon \oint_{s} \overline{E} \cdot d\overline{s}}{-\int_{\text{low}}^{\text{high}} \overline{E} \cdot d\overline{l}} \qquad \underline{\text{Resistance-}} \ R = \frac{V}{I} = \frac{-\int_{\text{low}}^{\text{high}} \overline{E} \cdot d\overline{l}}{\oint_{s} \overline{J} \cdot d\overline{s}} = \frac{-\int_{\text{low}}^{\text{high}} \overline{E} \cdot d\overline{l}}{\sigma \oint_{s} \overline{E} \cdot d\overline{s}}$$

## EE 381 Electric and Magnetic Fields Quiz #10 (Fall 2024)

Name Key B

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Eager for a snack, Earl Engineer places cranberry sauce (a tart concoction of cranberries, water, spices & sugar  $\Rightarrow \varepsilon = 66\varepsilon_0$ ,  $\sigma = 0.02$  S/m) between large circular metal plates at z = 0 and z = 2 cm. To warm the sauce, he connects a dual-channel DC power supply to the plates, lower plate at +12 V and upper plate at -14 V. After 3 seconds, does Laplace's or Poisson's equation apply? Justify answer by finding the relaxation time for any initial free charges in the sauce. Find the potential, electric field, and current density in the cranberry sauce at

z=0 cm. Extra credit- Determine the *power density* in the sauce.

(Laplace's or Poisson's equation? (Circle correct answer)

 $W_{p} = \sigma / E/^{2} = 0.02 (1300)^{2} = 33,900 \, \text{m}^{3}$ 

 $T_{\rm relax} = 29.92 n \le$ 

V(z=0.4 cm) = 6.8 V

 $\bar{E} (z=0.4 \text{ cm}) = \sqrt{300} \text{ /m}$ 

 $\bar{J}$  (z=0.4 cm) = 97 26 A/m<sup>2</sup>

Extra - power density =  $\frac{33,800}{m^3}$ 

D

## Cylindrical Coordinates $(\rho, \phi, z)$

$$d\overline{l} = d\rho \, \hat{a}_{\rho} + \rho d\phi \, \hat{a}_{\phi} + dz \, \hat{a}_{z}$$

$$d\overline{s}_{\rho} = \rho \, d\phi \, dz \, \hat{a}_{\rho} \qquad d\overline{s}_{\phi} = d\rho \, dz \, \hat{a}_{\phi} \qquad d\overline{s}_{z} = \rho \, d\rho \, d\phi \, \hat{a}_{z}$$

$$dv = \rho \, d\rho \, d\phi \, dz$$

$$\overline{r} = \rho \, \hat{a}_{\rho} + z \, \hat{a}_{z} \quad \text{(Note: } \hat{a}_{\rho} \text{ has } \phi \text{ dependence)}$$

$$\overline{\nabla} \Phi = \hat{a}_{\rho} \frac{\partial \Phi}{\partial \rho} + \hat{a}_{\phi} \frac{1}{\rho} \frac{\partial \Phi}{\partial \phi} + \hat{a}_{z} \frac{\partial \Phi}{\partial z}$$

$$\overline{\nabla} \bullet \overline{A} = \frac{1}{\rho} \frac{\partial (\rho A_{\rho})}{\partial \rho} + \frac{1}{\rho} \frac{\partial A_{\phi}}{\partial \phi} + \frac{\partial A_{z}}{\partial z}$$

$$\overline{\nabla} \times \overline{A} = \hat{a}_{\rho} \left( \frac{1}{\rho} \frac{\partial A_{z}}{\partial \phi} - \frac{\partial A_{\phi}}{\partial z} \right) + \hat{a}_{\phi} \left( \frac{\partial A_{\rho}}{\partial z} - \frac{\partial A_{z}}{\partial \rho} \right) + \hat{a}_{z} \left( \frac{1}{\rho} \frac{\partial (\rho A_{\phi})}{\partial \rho} - \frac{1}{\rho} \frac{\partial A_{\rho}}{\partial \phi} \right)$$

$$\nabla^{2} \Phi = \frac{1}{\rho} \frac{\partial}{\partial \rho} \left( \rho \frac{\partial \Phi}{\partial \rho} \right) + \frac{1}{\rho^{2}} \frac{\partial^{2} \Phi}{\partial \phi^{2}} + \frac{\partial^{2} \Phi}{\partial z^{2}}$$

permeability of free space:  $\mu_0 = 4\pi \cdot 10^{-7}$  H/m permittivity of free space:  $\epsilon_0 = 8.8542 \times 10^{-12}$  F/m

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Poisson's equation  $\nabla^2 V = \frac{-\rho_v}{\varepsilon}$  and Laplace's equation  $\nabla^2 V = 0$ .

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